NSN 5961-00-044-5749

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View Online at https://aerobasegroup.com/nsn/5961-00-044-5749
Inclosure Material:
Metal
Overall Length:
0.520 inches
Overall Diameter:
1.250 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.190 inches
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
-80.0 collector to base voltage/static/emitter open and -65.0 collector to emitter voltage/static/base open and -80.0 collector to emitter
voltage, dc with base short-circuited to emitter and -40.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
Between 4.00 amperes source cutoff current and 15.00 amperes source cutoff current blank
Power Rating Per Characteristic:
150.0 watts small-signal input power, common-collector
Special Features:
Junction pattern arrangement: pnp
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/340 government specification
Shelf Life:
N/a
Unit Of Measure:

NI

Demilitarization:

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